

INTERNATIONAL GEMOLOGICAL INSTITUTE

ELECTRONIC COPY

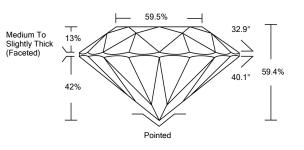
LABORATORY GROWN DIAMOND REPORT

April 28, 2022			
IGI Report Number	LG526285057		
Description	LABORATORY GROWN DIAMOND		
Shape and Cutting Style	ROUND BRILLIANT		
Measurements	6.45 - 6.47 X 3.83 MM		
GRADING RESULTS			
Carat Weight	1.00 CARAT		
Color Grade	Choile Police		
Clarity Grade	VVS 1		
Cut Grade	EXCELLENT		
ADDITIONAL GRADING INFORM	IATION		
Polish	EXCELLENT		
Symmetry	EXCELLENT		
Fluorescence	NONE		

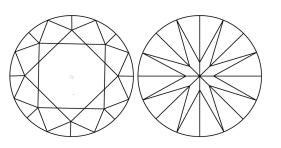
LABGROWN IGI LG526285057 Inscription(s) Comments: As Grown - No indication of post-growth treatment. This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

LG526285057

PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics. Green symbols indicate external characteristics. LABORATORY GROWN DIAMOND REPORT

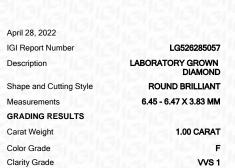
GRADING SCALES



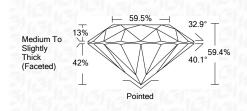
LABGROWN IGI LG526285057

LASERSCRIBE

Sample Image Used



EXCELLENT



ADDITIONAL GRADING INFORMATION

Cut Grade

Type

ROL

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	LABGROWN IGI LG526285057
Comments: As Grown treatment.	n - No indication of post-growth
	n Diamond was created by High erature (HPHT) growth process.



THIS DOCUMENT WAS PRODUCED WITH THE FOLLOWING SECURITY MEASURES: SPECIAL DOCUMENT PAPER, INK SCREINS, WATERMARK BACKGROUND DESIGNS, HOLOGRAM AND OTHER SECURITY FEATURES NOT LISTED AND DO EXCEED DOCUMENT SECURITY INDUSTRY GUIDELINES.



MM 1.00 CARAT		W81	EXCELLENT	59.4%	59.5%	Medium To Siightly Thick (Faceted)	Pointed	EXCELLENT	EXCELLENT	NONE	LABGROWN IGI LG528285057	As Growner. As Growner. As Growner, Wo Includion of park-growth man Laboratory Grown Diamond was created This Laboratory Grown Diamond was created growth processes. Uppel 1
6.45 - 6.47 X 3.83 MM Carat Weight	Color Grade	Clarity Grade	Cut Grade	Depth	Table	Girdle	Culet	Polish	Symmetry	Fluorescence	Inscription(s)	Comments: As Grown - No II treatment: This Laboratory by High Pressur growth process. Type II

